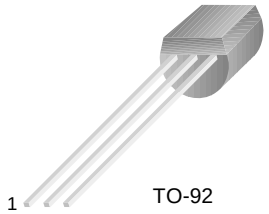
FAIRCHILD
SEMICONDUCTOR®

2N6519

High Voltage Transistor

- Collector-Emitter Voltage: V_{CEO}= -300V
- Collector Dissipation: P_C (max)=625mW



TO-92

1. Emitter 2. Base 3. Collector

PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	-300	V
V_{CEO}	Collector-Emitter Voltage	-300	V
V_{EBO}	Emitter-Base Voltage	-5	V
I_C	Collector Current	-500	mA
I_B	Base Current	-250	mA
P_C	Collector Power Dissipation	625	W
	Derate above 25°C	5	mW/°C
T_J	Junction Temperature	150	°C
T_{STG}	Storage Temperature	-55 ~ 150	°C

• Refer to 2N6520 for graphs

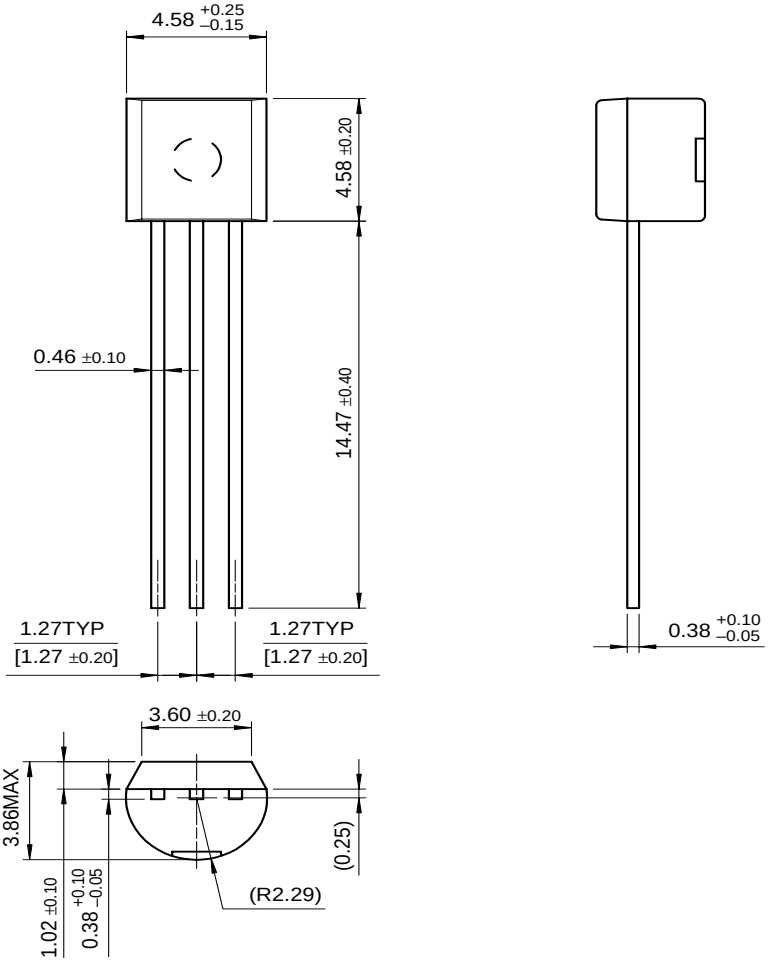
Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
BV_{CBO}	Collector-Base Breakdown Voltage	I_C= -100µA, I_E=0	-300		V
BV_{CEO}	* Collector-Emitter Breakdown Voltage	I_C= -1mA, I_B=0	-300		V
BV_{EBO}	Emitter-Base Breakdown Voltage	I_E= -10µA, I_C=0	-5		V
I_{CBO}	Collector Cut-off Current	V_{CB}= -200V, I_E=0		-50	nA
I_{EBO}	Emitter Cut-off Current	V_{EB}= -4V, I_C=0		-50	nA
h_{FE}	* DC Current Gain	V_{CE}= -10V, I_C= -1mA V_{CE}= -10V, I_C= -10mA V_{CE}= -10V, I_C= -30mA V_{CE}= -10V, I_C= -50mA V_{CE}= -10V, I_C= -100mA	30 45 45 40 20	 270 200	
V_{CE} (sat)	Collector-Emitter Saturation Voltage	I_C= -10mA, I_B= -1mA I_C= -20mA, I_B= -2mA I_C= -30mA, I_B= -3mA I_C= -50mA, I_B= -5mA		-0.30 -0.35 -0.50 -1	V V V V
V_{BE} (sat)	Base-Emitter Saturation Voltage	I_C= -10mA, I_B= -1mA I_C= -20mA, I_B= -2mA I_C= -30mA, I_B= -3mA		-0.75 -0.85 -0.90	V V V
V_{BE} (on)	Base-Emitter On Voltage	V_{CE}= -10V, I_C= -100mA		-2	V
f_T	* Current Gain Bandwidth Product	V_{CE}= -20V, I_C= -10mA, f=20MHz	40	200	MHz
C_{ob}	Output Capacitance	V_{CB}= -20V, I_E=0, f=1MHz		6	pF
C_{EB}	Emitter-Base Capacitance	V_{EB}= -0.5V, I_C=0, f=1MHz		100	pF
t_{ON}	Turn On Time	V_{BE} (off)= -2V, V_{CC}= -100V I_C= -50mA, I_{B1}= -10mA		200	ns
t_{OFF}	Turn Off Time	V_{CC}= -100V, I_C= -50mA I_{B1}=I_{B2}=10mA		3.5	ns

* Pulse Test: Pulse Width≤300µs, Duty Cycle≤2%

Package Dimensions

TO-92



Dimensions in Millimeters

TRADEMARKS

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

ACEx™	FACT™	ImpliedDisconnect™	PACMAN™	SPM™
ActiveArray™	FACT Quiet series™	ISOPLANAR™	POP™	Stealth™
Bottomless™	FAST®	LittleFET™	Power247™	SuperSOT™-3
CoolFET™	FASTr™	MicroFET™	PowerTrench®	SuperSOT™-6
CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
DOME™	GlobalOptoisolator™	MICROWIRE™	QS™	SyncFET™
EcoSPARK™	GTO™	MSX™	QT Optoelectronics™	TinyLogic®
E^2CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	I^2C™	OCX™	RapidConfigure™	UHC™
Across the board. Around the world.™		OCXPro™	RapidConnect™	UltraFET®
The Power Franchise™		OPTOLOGIC®	SILENT SWITCHER®	VCX™
Programmable Active Droop™		OPTOPLANAR™	SMART START™	

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.

2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.